

#### Shenzhen Huaxia Testing Technology Co., Ltd.

1F., Block A of Tongsheng Technology Building, Huahui Road, Dalang Street, Longhua District, Shenzhen, China

 Telephone:
 +86-755-26648640

 Fax:
 +86-755-26648637

 Website:
 www.cqa-cert.com

Report Template Version: V05 Report Template Revision Date: 2021-11-03

# **RF Exposure Evaluation Report**

Report No.: Applicant: Address of Applicant:	CQASZ20241202558E-02 Shenzhen Hollyland Technology Co., Ltd. 8F, Building 5D, Skyworth Innovation Valley, Tangtou Road, Shiyan Street, Baoan District, Shenzhen, 518055 China					
Equipment Under Test (EU	IT):					
EUT Name:	Wireless Microphone Charging Case					
Test Model No.:	M71C					
Model No.:	M71C					
Brand Name:	( HOLLYLAND					
FCC ID: Standards:	2ADZC-M71C 47 CFR Part 1.1307 47 CFR Part 2.1093 447498 D04 Interim General RF Exposure Guidance v01					
Date of Receipt:	2024-12-4					
Date of Test:	2024-12-4 to 2025-3-6					
Date of Issue:	2025-3-6					
Test Result:	PASS*					
*In the configuration tested	*In the configuration tested, the EUT complied with the standards specified above					

Tested By:	lewis zhou	
	( Lewis Zhou )	TESTING TEQU
Reviewed By:	Timo Lej'	
	( Timo Lei )	华夏准测
Approved By:	Janos	* APPROVED *
	( Jack Ai )	

The test report is effective only with both signature and specialized stamp, The result(s) shown in this report refer only to the sample(s) tested. Without written approval of CQA, this report can't be reproduced except in full.



# 1 Version

### **Revision History Of Report**

Report No.	Version	Description	Issue Date	
CQASZ20241202558E-02	Rev.01	Initial report	2025-3-6	



Page

# 2 Contents

1 VERSION	2
2 CONTENTS	3
3 GENERAL INFORMATION	
3.1 CLIENT INFORMATION	
3.2 GENERAL DESCRIPTION OF EUT	
3.3 GENERAL DESCRIPTION OF BLE	4
4 SAR EVALUATION	5
4.1 RF Exposure Compliance Requirement 4.1.1 Standard Requirement	5
4.1.1 Standard Requirement	5
4.1.2 Limits	5
4.1.3 EUT RF Exposure	7



# **3** General Information

### 3.1 Client Information

Applicant:	Shenzhen Hollyland Technology Co., Ltd.
Address of Applicant:	8F, Building 5D, Skyworth Innovation Valley, Tangtou Road, Shiyan Street, Baoan District, Shenzhen, 518055 China
Manufacturer:	Shenzhen Hollyland Technology Co., Ltd.
Address of Manufacturer:	8F, Building 5D, Skyworth Innovation Valley, Tangtou Road, Shiyan Street, Baoan District, Shenzhen, 518055 China
Factory:	Shenzhen Hollyland Technology Co., Ltd.
Address of Factory:	8F, Building 5D, Skyworth Innovation Valley, Tangtou Road, Shiyan Street, Baoan District, Shenzhen, 518055 China

### 3.2 General Description of EUT

Product Name:	Wireless Microphone Charging Case
Model No.:	M71C
Test Model No	M71C
Trade Mark:	
EUT Supports Radios application:	Bluetooth mode 2402-2480MHz
Software Version:	HLD_A6701_028_S1.0.0.24_BurnFiles_Common_20250118_Box
Hardware Version:	V38
Sample Type:	□ Mobile
EUT Power Supply:	Li-ion battery: DC 3.8V 2000mAh, Charge by DC 5V for adapter

### 3.3 General Description of BLE

Operation Frequency:	2402MHz~2480MHz
Bluetooth Version:	V5.0
Modulation Technique:	Non Frequency Hopping Spread Spectrum(NFHSS)
Modulation Type:	GFSK
Number of Channel:	BLE:40
Transfer Rate:	BLE:1Mbps
Test Software of EUT:	FCC_Tool_V3.01
Antenna Type:	Ceramic antenna
Antenna Gain:	2.71dBi





## 4 SAR Evaluation

#### 4.1 RF Exposure Compliance Requirement

#### 4.1.1 Standard Requirement

447498 D04 Interim General RF Exposure Guidance v01

3.2. SAR Test Reduction Guidance

SAR test reduction procedures [Glossary] allow using a particular set of test data as representative of other, similar, test conditions. This may be applied for data within different test positions (e.g. body, head, extremity), wireless modes (e.g. Wi-Fi, cellular), and frequency bands. This test reduction process provides for the use of test data for one specific channel, while referencing to those data for demonstrating compliance in other required channels for each test position of an exposure condition, within the operating mode of a frequency band. This is limited specifically to when the reported 1-g or 10-g SAR for the mid-band or highest output power channel meets any of the following conditions.

#### 4.1.2 Limits

SAR-based thresholds are derived based on frequency, power, and separation distance of the RF source. The formula defines the thresholds in general for either available maximum time averaged power or maximum time-averaged ERP, whichever is greater.

If the ERP of a device is not easily determined, such as for a portable device with a small form factor, the applicant may use the available maximum time-averaged power exclusively if the device antenna or radiating structure does not exceed an electrical length of  $\lambda/4$ .

As for devices with antennas of length greater than  $\lambda$  /4 where the gain is not well defined, but always less than that of a half-wave dipole (length  $\lambda$  /2), the available maximum time-averaged power generated by the device may be used in place of the maximum time-averaged ERP, where that value is not known.

The separation distance is the smallest distance from any part of the antenna or radiating structure for all persons, during operation at the applicable ERP. In the case of mobile or portable devices, the separation distance is from the outer housing of the device where it is closest to the antenna.

The SAR-based exemption formula of § 1.1307(b)(3)(i)(B), repeated here as Formula (B.2), applies for single fixed, mobile, and portable RF sources with available maximum time-averaged power or effective radiated power (ERP), whichever is greater, of less than or equal to the threshold Pth (mW).

This method shall only be used at separation distances from 0.5 cm to 40 cm and at frequencies from 0.3 GHz to 6 GHz (inclusive). Pth is given by Formula (B.2).



$$P_{\rm th} \,({\rm mW}) = \begin{cases} ERP_{20\,\rm cm} (d/20\,\rm cm)^x & d \le 20\,\rm cm \\ \\ ERP_{20\,\rm cm} & 20\,\rm cm < d \le 40\,\rm cm \end{cases}$$
(B.2)

where

$$x = -\log_{10}\left(\frac{60}{ERP_{20} \operatorname{cm}\sqrt{f}}\right)$$

and f is in GHz, d is the separation distance (cm), and  $ERP_{20cm}$  is per Formula (B.1). The example values shown in Table B.2 are for illustration only.

					Di	stance	(mm)				
		5	10	15	20	25	30	35	40	45	50
(Z	300	39	65	88	110	129	148	166	184	201	217
(MHz)	450	22	44	67	89	112	135	158	180	203	226
	835	9	25	44	66	90	116	145	175	207	240
enc	1900	3	12	26	44	66	92	122	157	195	236
Frequency	2450	3	10	22	38	59	83	111	143	179	219
Fr	3600	2	8	18	32	49	71	96	125	158	195
-	5800	1	6	14	25	40	58	80	106	136	169

Table B.2-Example Power Thresholds (mW)



#### 4.1.3 EUT RF Exposure

#### Measurement Data

Channel	Conducted Peak Output Power (dBm)	EIRP (dBm)	ERP (dBm)	ERP (mW)	Exclusion threshold (mW)
Lowest (2402MHz)	-4.41	-1.70	-3.85	0.41	2.8
Middle (2440MHz)	-4.18	-1.47	-3.62	0.43	2.8
Highest (2480MHz)	-2.74	-0.03	-2.18	0.61	2.7

Remark: The Max Conducted Peak Output Power data refer to report Report No.: CQASZ20241202558E-01.

\*\*\* END OF REPORT \*\*\*